

Code No: NR320404

NR

Set No. 2

III B.Tech II Semester Examinations, December 2010

VLSI TECHNOLOGY

Common to Electronics And Telematics, Electronics And Communication Engineering

Time: 3 hours

Max Marks: 80

Answer any FIVE Questions
All Questions carry equal marks

1. (a) Explain channel formation in case of depletion mode MOS transistors and how the transistor action differs from enhancement mode transistor.
(b) Explain how a bi polar npn transistor is included in n well CMOS processing. Draw the cross section of Bi CMOS transistor. [6+10]
2. (a) Prove that the combination of BJT and MOS technology offers the best performance in Analog VLSI design.
(b) Draw the block diagram of D/A converter suitable for VLSI Analog Circuits and explain. [8+8]
3. Explain about the design approaches for full custom and semi custom Devices. [16]
4. (a) Explain the various methods used to test sequential Logic.
(b) Distinguish between simulator and circuit extractor. [8+8]
5. (a) Write a note on the general observation about design rules.
(b) What are contact cuts? Explain buried and but contacts with cross sectional and top view diagrams. [8+8]
6. (a) Explain ceramic package types with their cross sectional sketches.
(b) Why package sealing is required in packing and how it is done? [8+8]
7. (a) What are the different types of programmable inter connection channels used for routing parts in FPGAs? Explain.
(b) Explain about anti fuses used in FPGAs. [8+8]
8. Briefly explain the following verification tools:
 - (a) timing verifiers
 - (b) design rule checkers
 - (c) layout extractions and
 - (d) test vectors. [4+4+4+4]

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Set No. 4

III B.Tech II Semester Examinations, December 2010

VLSI TECHNOLOGY

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(b) Explain how a bi polar npn transistor is included in n well CMOS processing. Draw the cross section of Bi CMOS transistor. [6+10]
8. Explain about the design approaches for full custom and semi custom Devices. [16]

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Set No. 1

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VLSI TECHNOLOGY

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- (a) timing verifiers
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- (c) layout extractions and
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[4+4+4+4]

2. (a) What are the different types of programmable inter connection channels used for routing parts in FPGAs? Explain.

(b) Explain about anti fuses used in FPGAs. [8+8]

3. (a) Explain ceramic package types with their cross sectional sketches.

(b) Why package sealing is required in packing and how it is done? [8+8]

4. (a) Explain channel formation in case of depletion mode MOS transistors and how the transistor action differs from enhancement mode transistor.

(b) Explain how a bi polar npn transistor is included in n well CMOS processing. Draw the cross section of Bi CMOS transistor. [6+10]

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(b) Distinguish between simulator and circuit extractor. [8+8]

8. (a) Prove that the combination of BJT and MOS technology offers the best performance in Analog VLSI design.

(b) Draw the block diagram of D/A converter suitable for VLSI Analog Circuits and explain. [8+8]

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Set No. 3

III B.Tech II Semester Examinations, December 2010

VLSI TECHNOLOGY

Common to Electronics And Telematics, Electronics And Communication Engineering

Time: 3 hours

Max Marks: 80

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All Questions carry equal marks

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(b) Draw the block diagram of D/A converter suitable for VLSI Analog Circuits and explain. [8+8]
2. (a) Write a note on the general observation about design rules.
(b) What are contact cuts? Explain buried and but contacts with cross sectional and top view diagrams. [8+8]
3. (a) What are the different types of programmable inter connection channels used for routing parts in FPGAs? Explain.
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